

Parameter	Value
V_{CEO}	12V
I_C	500mA

●Outline

VMT3	EMT3
2SC5663 SC-105AA	2SC5585 SOT-416

●Features

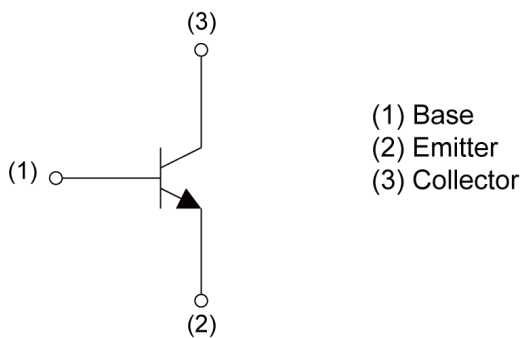
- 1)High current.
- 2)Low $V_{CE(sat)}$
 $V_{CE(sat)} \leq 250mV$ at $I_C=200mA/I_B=10mA$

●Application

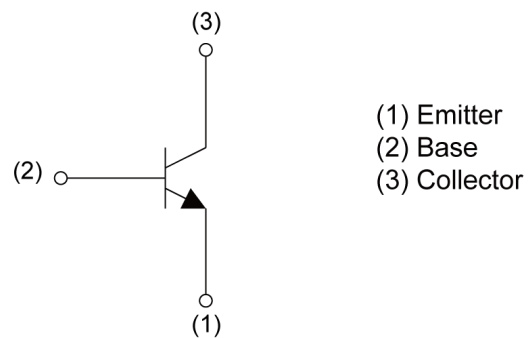
LOW FREQUENCY AMPLIFIER, DRIVER

●Inner circuit

2SC5663



2SC5585



●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SC5663	VMT3	1212	T2L	180	8	8000	BX
2SC5585	EMT3	1616	TL	180	8	3000	BX

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	15	V
Collector-emitter voltage		V_{CEO}	12	V
Emitter-base voltage		V_{EBO}	6	V
Collector current		I_{C}	500	mA
		I_{CP}^{*1}	1.0	A
Power dissipation	2SC5663	P_{D}^{*2}	150	mW
	2SC5585		150	
Junction temperature		T_{j}	150	$^\circ\text{C}$
Range of storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_{\text{C}} = 10\mu\text{A}$	15	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_{\text{C}} = 1\text{mA}$	12	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_{\text{E}} = 10\mu\text{A}$	6	-	-	V
Collector cut-off current	I_{CBO}	$V_{\text{CB}} = 15\text{V}$	-	-	100	nA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}} = 6\text{V}$	-	-	100	nA
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = 200\text{mA}, I_{\text{B}} = 10\text{mA}$	-	90	250	mV
DC current gain	h_{FE}	$V_{\text{CE}} = 2\text{V}, I_{\text{C}} = 10\text{mA}$	270	-	680	-
Transition frequency	f_{T}	$V_{\text{CE}} = 2\text{V}, I_{\text{E}} = -10\text{mA}, f = 100\text{MHz}$	-	320	-	MHz
Output capacitance	C_{ob}	$V_{\text{CB}} = 10\text{V}, I_{\text{E}} = 0\text{A}, f = 1\text{MHz}$	-	7.5	-	pF

*1 $P_{\text{w}}=1\text{ms}$, Single Pulse.

*2 Each terminal mounted on a reference land.

● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.1 Ground Emitter Propagation Characteristics

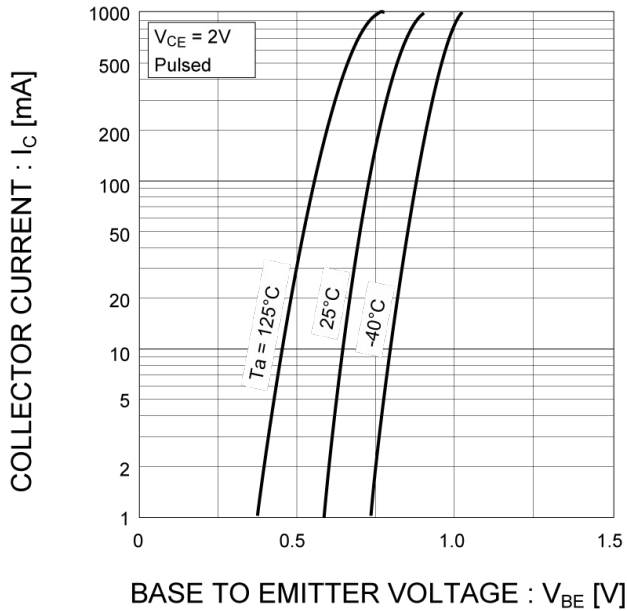


Fig.2 Typical Output Characteristics

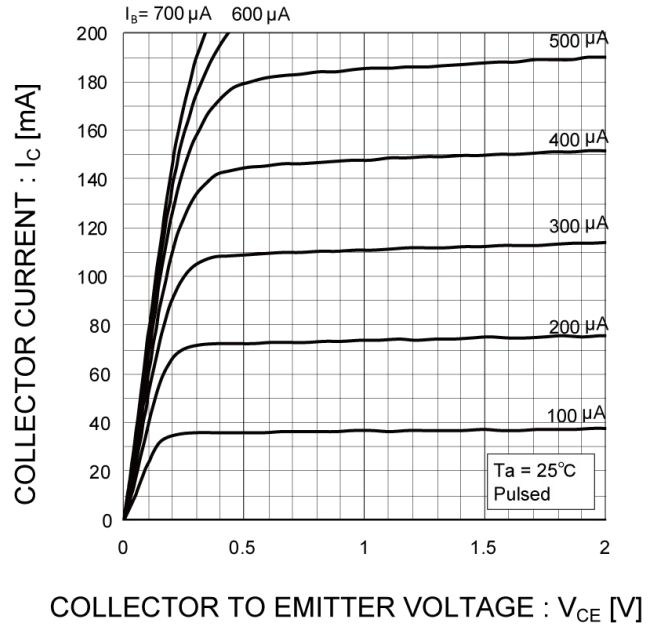


Fig.3 DC Current Gain vs. Collector Current (I)

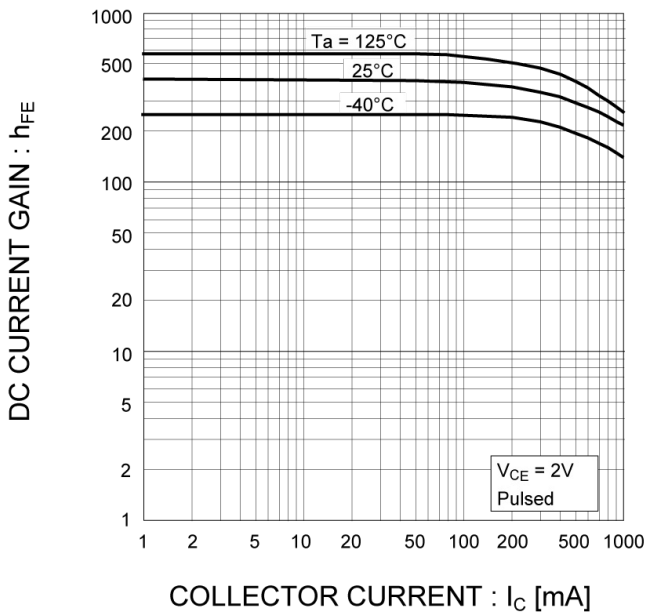
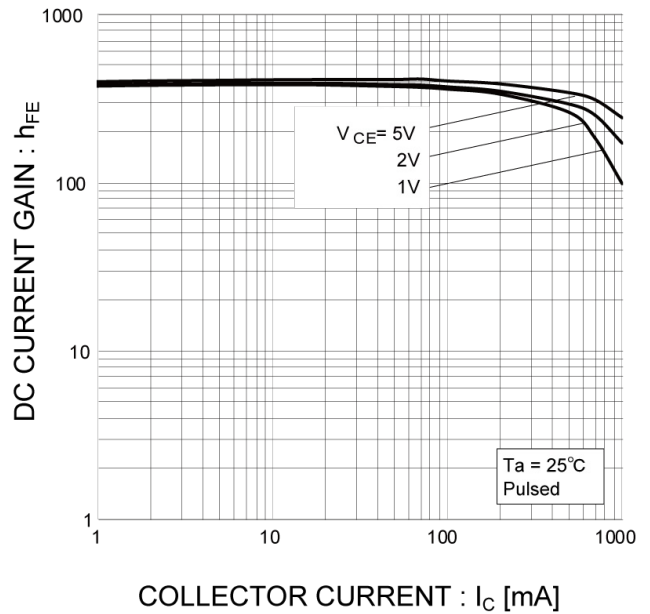


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

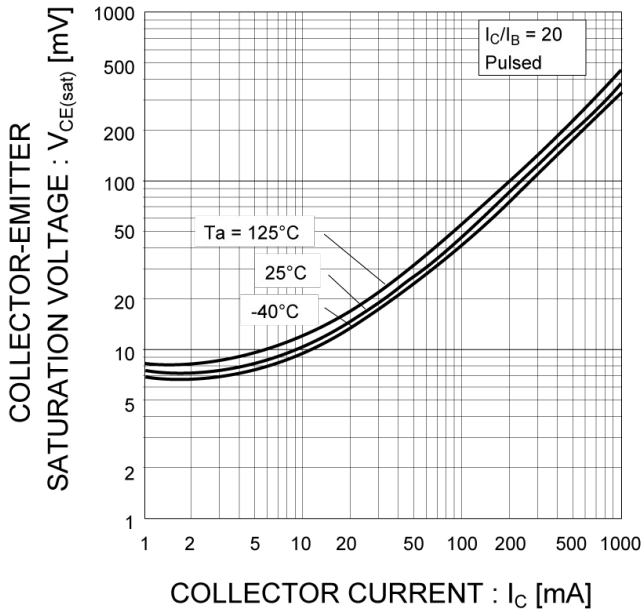


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

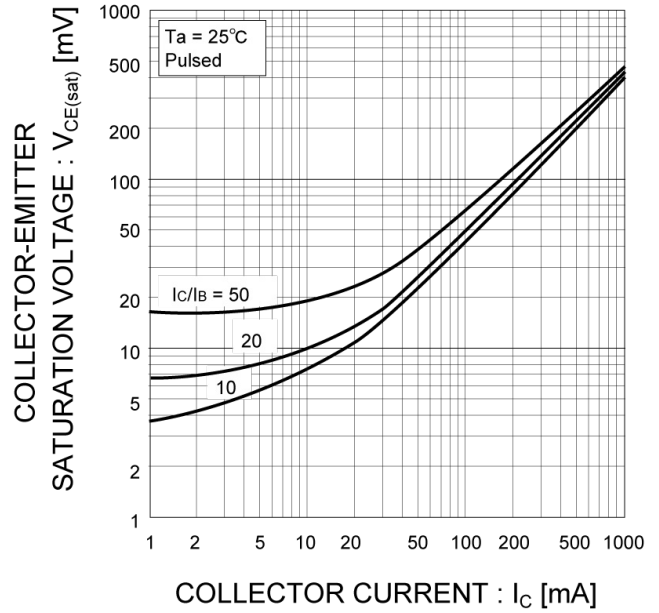


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

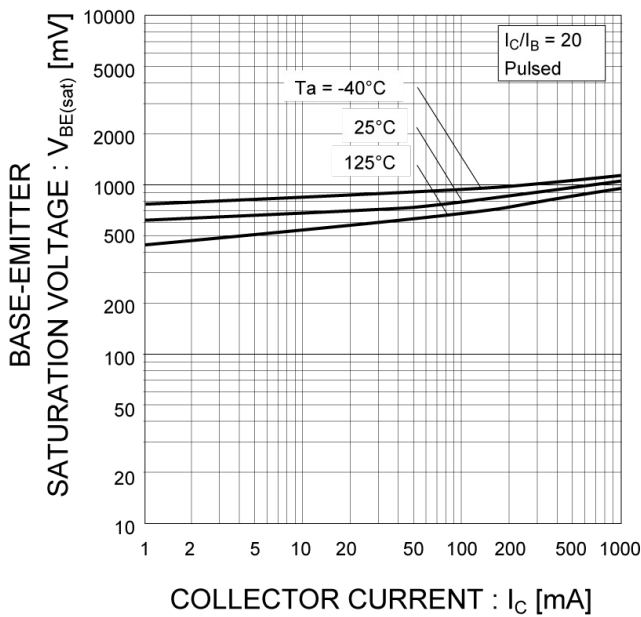
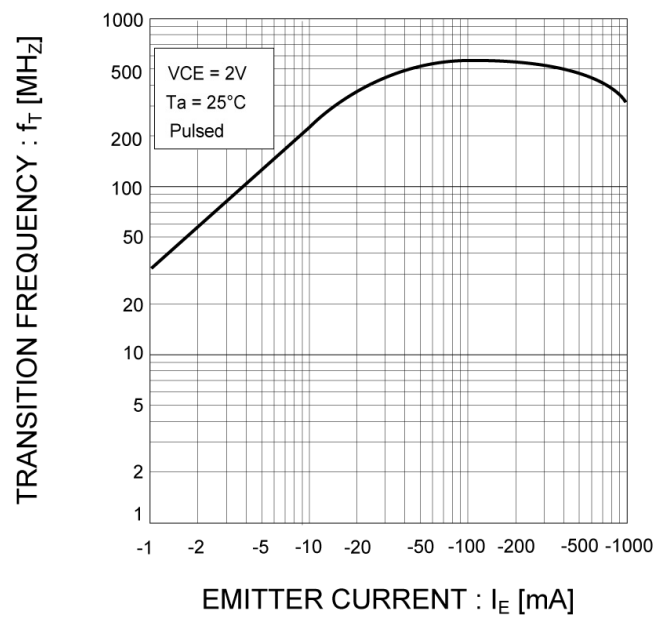


Fig.8 Gain Bandwidth Product vs. Emitter Current



●Electrical characteristic curves($T_a = 25^\circ\text{C}$)

Fig.9 Emitter Input Capacitance vs. Emitter-Base Voltage
Collector Output Capacitance vs. Collector-Base Voltage

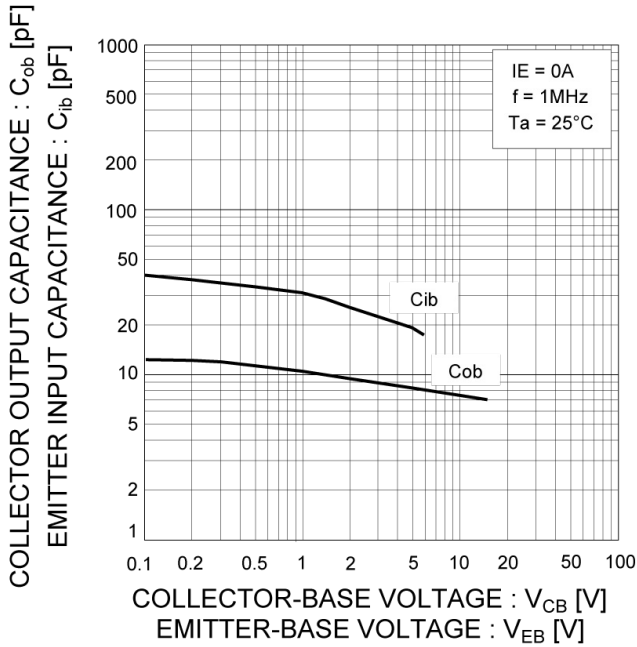


Fig.10 Safe Operating Area

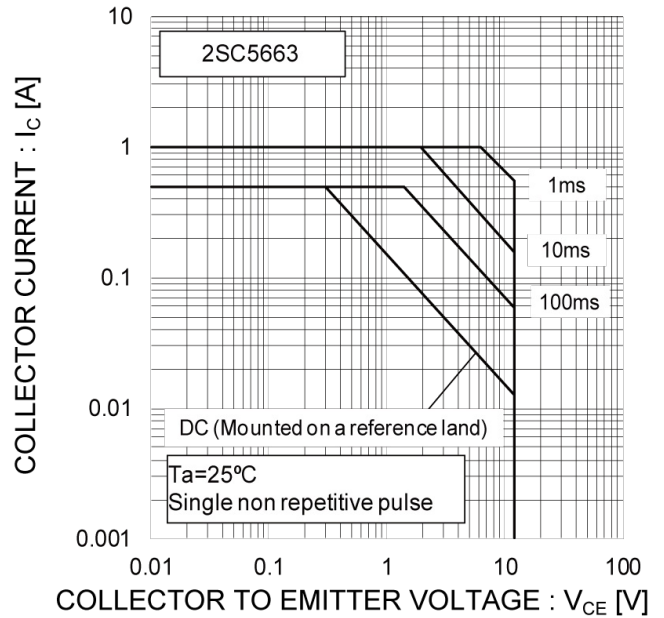
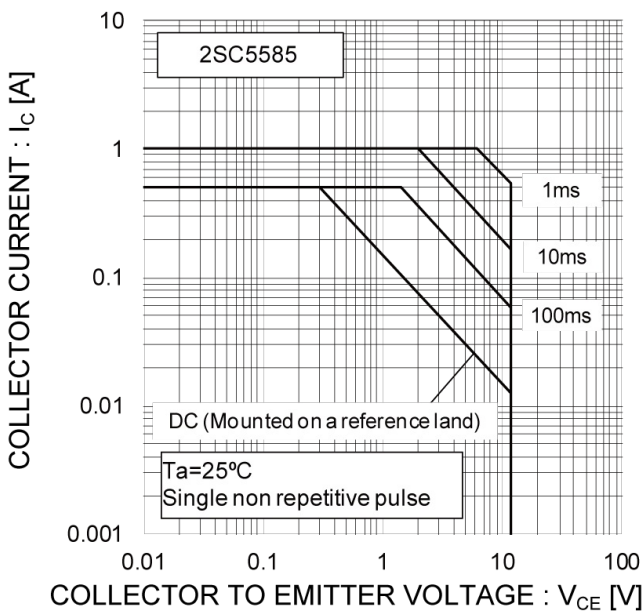
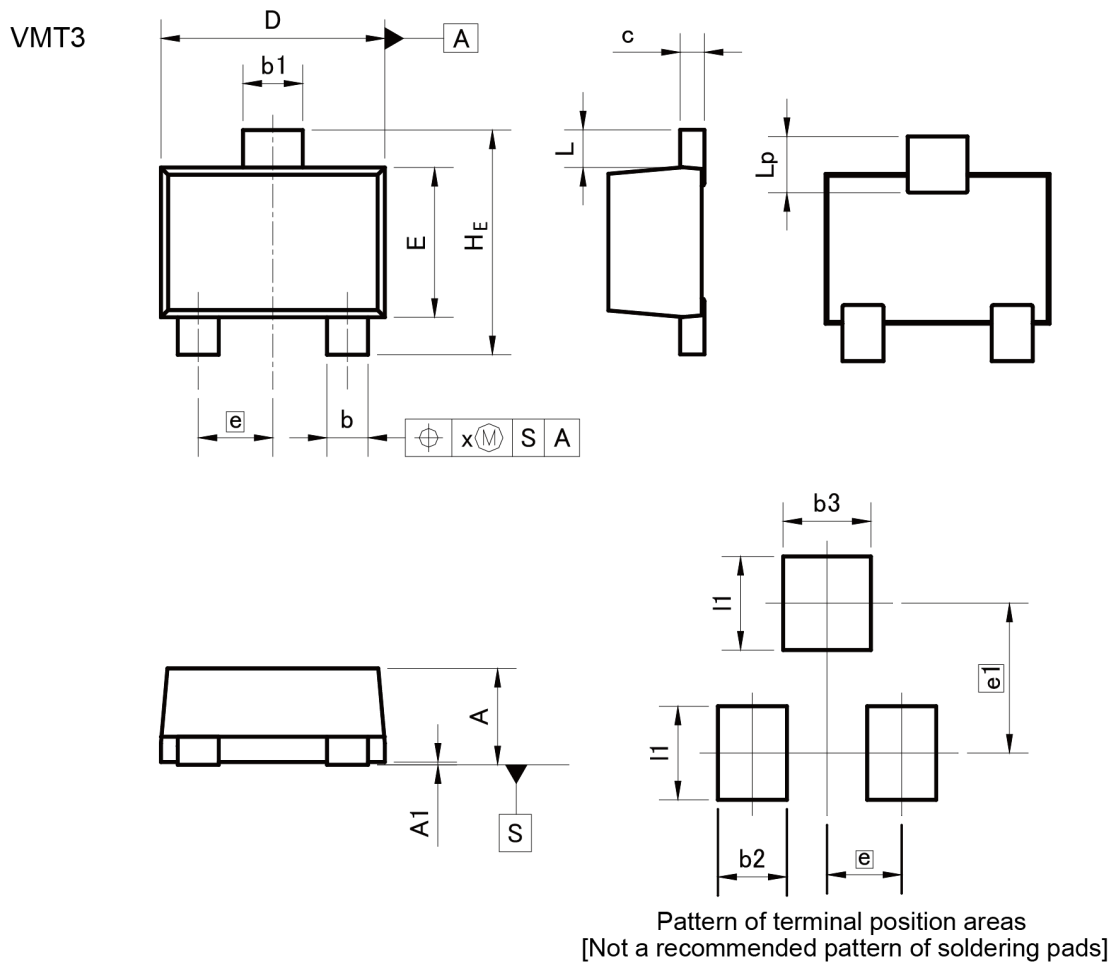


Fig.11 Safe Operating Area



●Dimensions



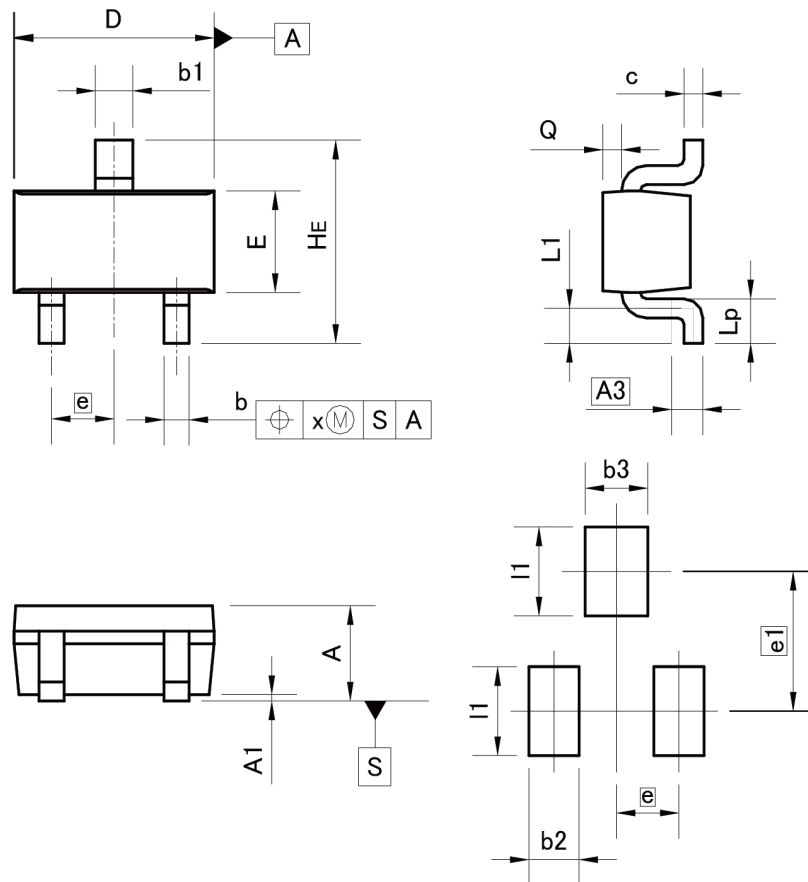
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
e	0.40		0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
b3	-	0.47	-	0.019
e1	0.80		0.031	
l1	-	0.50	-	0.020

Dimension in mm/inches

●Dimensions

EMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
e	0.50		0.020	
HE	1.40	1.80	0.055	0.071
L1	0.10	-	0.004	-
Lp	0.15	-	0.006	-
Q	0.05	0.25	0.002	0.010
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.40	-	0.016
b3	-	0.50	-	0.020
e1	1.10		0.043	
l1	-	0.70	-	0.028

Dimension in mm/inches

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